

## IRS2109/IRS21094(S)PbF

### HALF-BRIDGE DRIVER

#### Features

- Floating channel designed for bootstrap operation
- Fully operational to +600 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout for both channels
- 3.3 V, 5 V, and 15 V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- High-side output in phase with IN input
- Logic and power ground +/- 5 V offset.
- Internal 540 ns deadtime, and programmable up to 5  $\mu$ s with one external  $R_{DT}$  resistor (IRS21094)
- Lower di/dt gate driver for better noise immunity
- Shutdown input turns off both channels.
- RoHS compliant

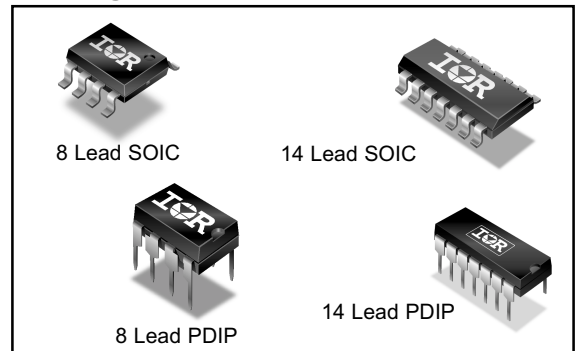
#### Description

The IRS2109/IRS21094 are high voltage, high speed power MOSFET and IGBT drivers with dependent high- and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600 V.

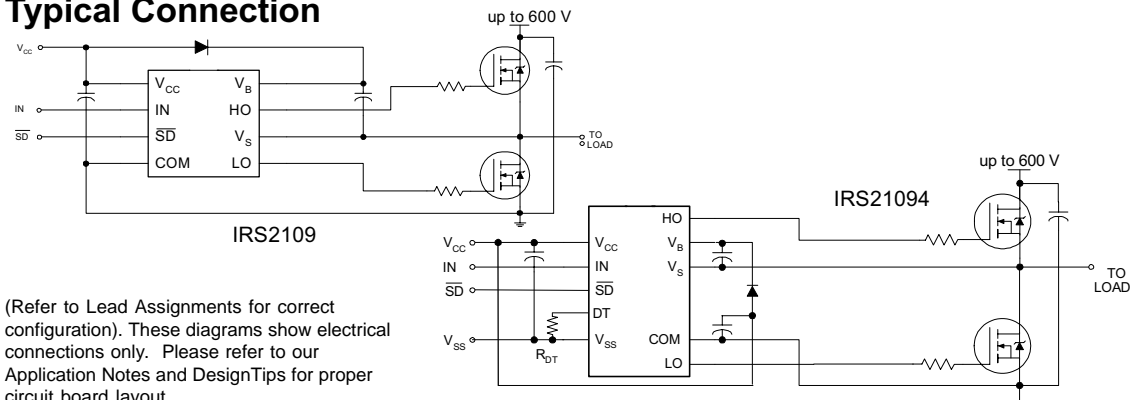
#### Product Summary

|                     |   |
|---------------------|---|
| $V_{OFFSET}$        | 600 V max.  |
| $I_{O+/-}$          | 120 mA / 250 mA                                       |
| $V_{OUT}$           | 10 V - 20 V   |
| $t_{on/off}$ (typ.) | 750 ns & 200 ns                                       |
| Deadtime            | 540 ns<br>(programmable up to 5 $\mu$ s for IRS21094) |

#### Packages



#### Typical Connection



## Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol              | Definition  | Min.                  | Max.                  | Units |      |
|---------------------|---|-----------------------|-----------------------|-------|------|
| V <sub>B</sub>      | High-side floating absolute voltage                 | -0.3                  | 625                   | V     |      |
| V <sub>S</sub>      | High-side floating supply offset voltage            | V <sub>B</sub> - 25   | V <sub>B</sub> + 0.3  |       |      |
| V <sub>HO</sub>     | High-side floating output voltage                   | V <sub>S</sub> - 0.3  | V <sub>B</sub> + 0.3  |       |      |
| V <sub>CC</sub>     | Low-side and logic fixed supply voltage             | -0.3                  | 25                    |       |      |
| V <sub>LO</sub>     | Low-side output voltage                             | -0.3                  | V <sub>CC</sub> + 0.3 |       |      |
| DT                  | Programmable deadtime pin voltage (IRS21094 only)   | V <sub>SS</sub> - 0.3 | V <sub>CC</sub> + 0.3 |       |      |
| V <sub>IN</sub>     | Logic input voltage (IN & $\overline{SD}$ )         | V <sub>SS</sub> - 0.3 | V <sub>CC</sub> + 0.3 |       |      |
| V <sub>SS</sub>     | Logic ground (IRS21094/IRS21894 only)               | V <sub>CC</sub> - 25  | V <sub>CC</sub> + 0.3 |       |      |
| dV <sub>S</sub> /dt | Allowable offset supply voltage transient           | —                     | 50                    | V/ns  |      |
| PD                  | Package power dissipation @ T <sub>A</sub> ≤ +25 °C | (8 Lead PDIP)         | —                     | 1.0   | W    |
|                     |   | (8 Lead SOIC)         | —                     | 0.625 |      |
|                     |   | (14 lead PDIP)        | —                     | 1.6   |      |
|                     |   | (14 lead SOIC)        | —                     | 1.0   |      |
| R <sub>thJA</sub>   | Thermal resistance, junction to ambient             | (8 Lead PDIP)         | —                     | 125   | °C/W |
|                     |   | (8 Lead SOIC)         | —                     | 200   |      |
|                     |   | (14 lead PDIP)        | —                     | 75    |      |
|                     |   | (14 lead SOIC)        | —                     | 120   |      |
| T <sub>J</sub>      | Junction temperature                                | —                     | 150                   | °C    |      |
| T <sub>S</sub>      | Storage temperature                                 | -50                   | 150                   |       |      |
| T <sub>L</sub>      | Lead temperature (soldering, 10 seconds)            | —                     | 300                   |       |      |

## Recommended Operating Conditions

The input/output logic timing diagram is shown in Fig. 1. For proper operation the device should be used within the recommended conditions. The  $V_S$  and  $V_{SS}$  offset rating are tested with all supplies biased at a 15 V differential.

| Symbol   | Definition  | Min.       | Max.       | Units |
|----------|---|------------|------------|-------|
| $V_B$    | High-side floating supply absolute voltage        | $V_S + 10$ | $V_S + 20$ | V     |
| $V_S$    | High-side floating supply offset voltage          | (Note 1)   | 600        |       |
| $V_{HO}$ | High-side floating output voltage                 | $V_S$      | $V_B$      |       |
| $V_{CC}$ | Low-side and logic fixed supply voltage           | 10         | 20         |       |
| $V_{LO}$ | Low-side output voltage                           | 0          | $V_{CC}$   |       |
| $V_{IN}$ | Logic input voltage (IN & $\overline{SD}$ )       | $V_{SS}$   | $V_{CC}$   |       |
| DT       | Programmable deadtime pin voltage (IRS21094 only) | $V_{SS}$   | $V_{CC}$   |       |
| $V_{SS}$ | Logic ground (IRS21094 only)                      | -5         | 5          | °C    |
| $T_A$    | Ambient temperature                               | -40        | 125        |       |

Note 1: Logic operational for  $V_S$  of -5 V to +600 V. Logic state held for  $V_S$  of -5 V to  $-V_{BS}$ . (Please refer to the Design Tip DT97-3 for more details).

## Dynamic Electrical Characteristics

$V_{BIAS} (V_{CC}, V_{BS}) = 15\text{ V}$ ,  $V_{SS} = \text{COM}$ ,  $C_L = 1000\text{ pF}$ ,  $T_A = 25\text{ °C}$ , DT =  $V_{SS}$  unless otherwise specified.

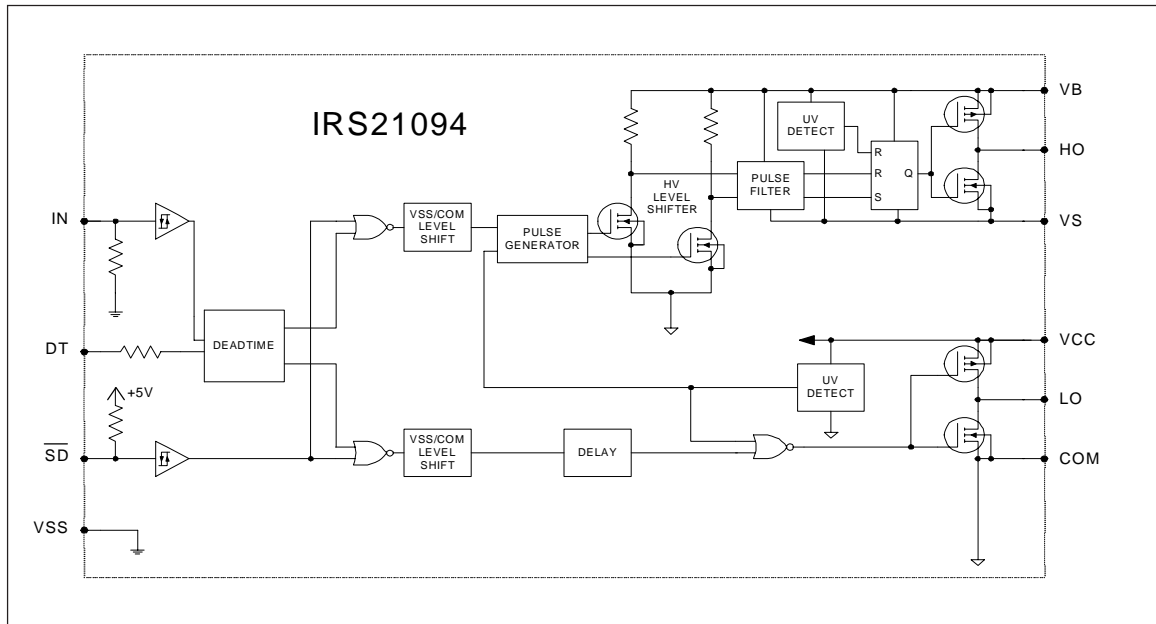
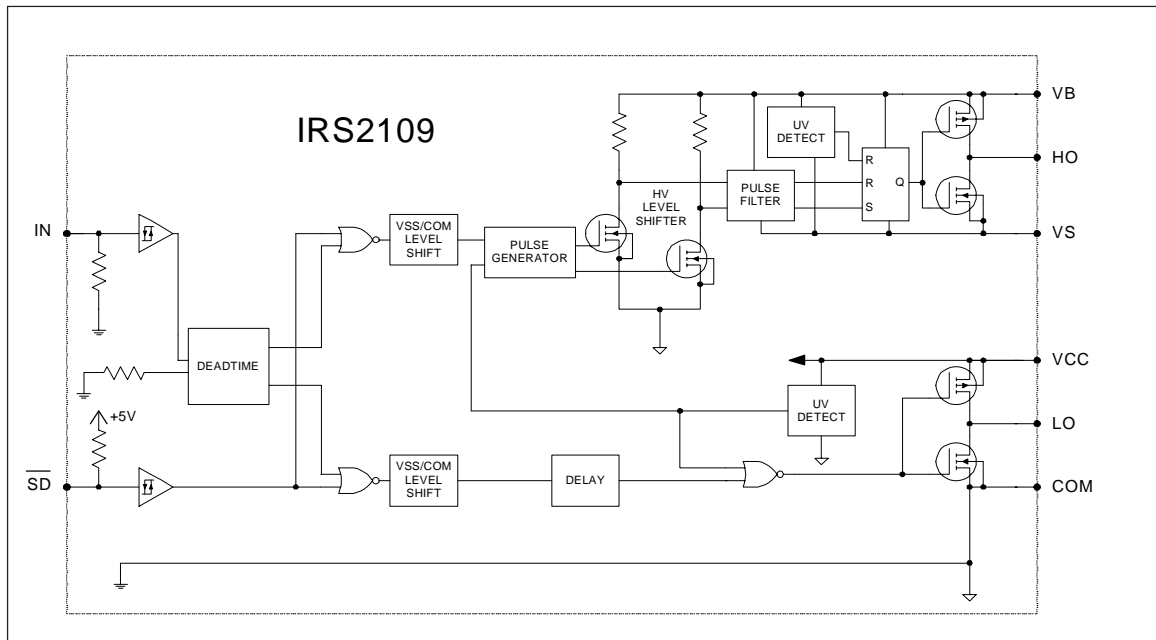
| Symbol    | Definition  | Min. | Typ. | Max. | Units         | Test Conditions                          |
|-----------|---|------|------|------|---------------|--|
| $t_{on}$  | Turn-on propagation delay   | —    | 750  | 950  | ns            | $V_S = 0\text{ V}$                       |
| $t_{off}$ | Turn-off propagation delay  | —    | 200  | 280  |               | $V_S = 0\text{ V or } 600\text{ V}$      |
| $t_{sd}$  | Shutdown propagation delay  | —    | 200  | 280  |               | $V_S = 0\text{ V}$                       |
| MT        | Delay matching, HS & LS turn-on/off   | —    | 0    | 70   |               |  |
| $t_r$     | Turn-on rise time   | —    | 100  | 220  |               |  |
| $t_f$     | Turn-off fall time  | —    | 35   | 80   |               | $R_{DT} = 0\ \Omega$                     |
| DT        | Deadtime: LO turn-off to HO turn-on (DT <sub>LO-HO</sub> ) & HO turn-off to LO turn-on (DT <sub>HO-LO</sub> ) | 400  | 540  | 680  | $\mu\text{s}$ | $R_{DT} = 200\text{ k}\Omega$ (IRS21094) |
|           |   | 4    | 5    | 6    |               | $R_{DT} = 0\ \Omega$                     |
| MDT       | Deadtime matching = DT <sub>LO-HO</sub> - DT <sub>HO-LO</sub>   | —    | 0    | 60   | ns            | $R_{DT} = 0\ \Omega$                     |
|           |   | —    | 0    | 600  |               | $R_{DT} = 200\text{ k}\Omega$ (IRS21094) |

### Static Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15 V,  $V_{SS}$  = COM,  $DT = V_{SS}$  and  $T_A = 25^\circ\text{C}$  unless otherwise specified. The  $V_{IL}$ ,  $V_{IH}$ , and  $I_{IN}$  parameters are referenced to  $V_{SS}/\text{COM}$  and are applicable to the respective input leads: IN and  $\overline{SD}$ . The  $V_O$ ,  $I_O$ , and  $R_{on}$  parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

| Symbol                     | Definition   | Min. | Typ. | Max. | Units         | Test Conditions  |
|----------------------------|--|------|------|------|---------------|--|
| $V_{IH}$                   | Logic "1" input voltage for HO & logic "0" for LO                  | 2.5  | —    | —    | V             | $V_{CC} = 10\text{ V to } 20\text{ V}$                       |
| $V_{IL}$                   | Logic "0" input voltage for HO & logic "1" for LO                  | —    | —    | 0.8  |               |  |
| $V_{SD,TH+}$               | $\overline{SD}$ input positive going threshold                     | 2.5  | —    | —    |               |  |
| $V_{SD,TH-}$               | $\overline{SD}$ input negative going threshold                     | —    | —    | 0.8  |               |  |
| $V_{OH}$                   | High level output voltage, $V_{BIAS} - V_O$                        | —    | 0.05 | 0.2  |               |  |
| $V_{OL}$                   | Low level output voltage, $V_O$                                    | —    | 0.02 | 0.1  |               | $I_O = 2\text{ mA}$  |
| $I_{LK}$                   | Offset supply leakage current                                      | —    | —    | 50   | $\mu\text{A}$ | $V_B = V_S = 600\text{ V}$                                   |
| $I_{QBS}$                  | Quiescent $V_{BS}$ supply current                                  | 20   | 75   | 130  |               | $V_{IN} = 0\text{ V or } 5\text{ V}$                         |
| $I_{QCC}$                  | Quiescent $V_{CC}$ supply current                                  | 0.4  | 1.0  | 1.6  | mA            | $V_{IN} = 0\text{ V or } 5\text{ V}$<br>$R_{DT} = 0\ \Omega$ |
| $I_{IN+}$                  | Logic "1" input bias current                                       | —    | 5    | 20   | $\mu\text{A}$ | $IN = 5\text{ V}, \overline{SD} = 0\text{ V}$                |
| $I_{IN-}$                  | Logic "0" input bias current                                       | —    | —    | 2    |               | $IN = 0\text{ V}, \overline{SD} = 5\text{ V}$                |
| $V_{CCUV+}$<br>$V_{BSUV+}$ | $V_{CC}$ and $V_{BS}$ supply undervoltage positive going threshold | 8.0  | 8.9  | 9.8  | V             |  |
| $V_{CCUV-}$<br>$V_{BSUV-}$ | $V_{CC}$ and $V_{BS}$ supply undervoltage negative going threshold | 7.4  | 8.2  | 9.0  |               |  |
| $V_{CCUVH}$<br>$V_{BSUVH}$ | Hysteresis   | 0.3  | 0.7  | —    |               |  |
| $I_{O+}$                   | Output high short circuit pulsed current                           | 120  | 290  | —    | mA            | $V_O = 0\text{ V}, PW \leq 10\ \mu\text{s}$                  |
| $I_{O-}$                   | Output low short circuit pulsed current                            | 250  | 600  | —    |               | $V_O = 15\text{ V}, PW \leq 10\ \mu\text{s}$                 |

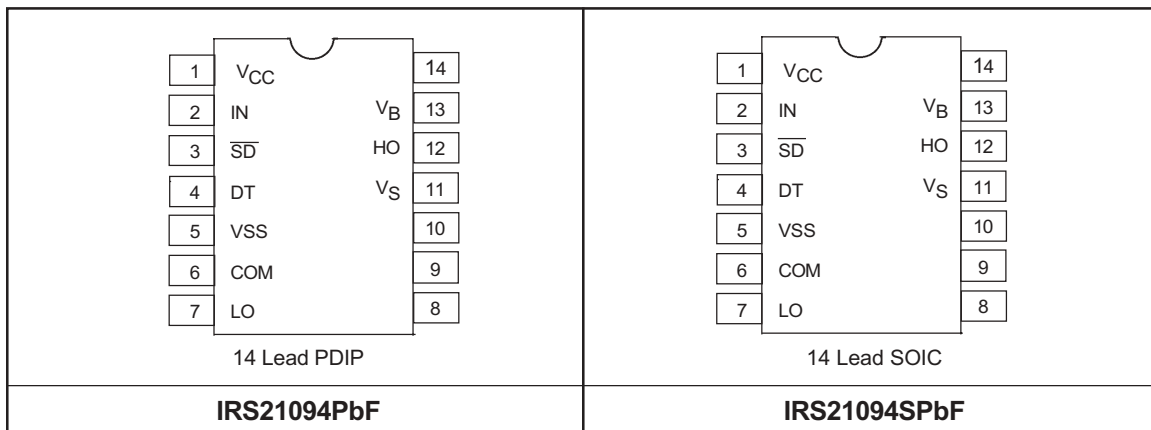
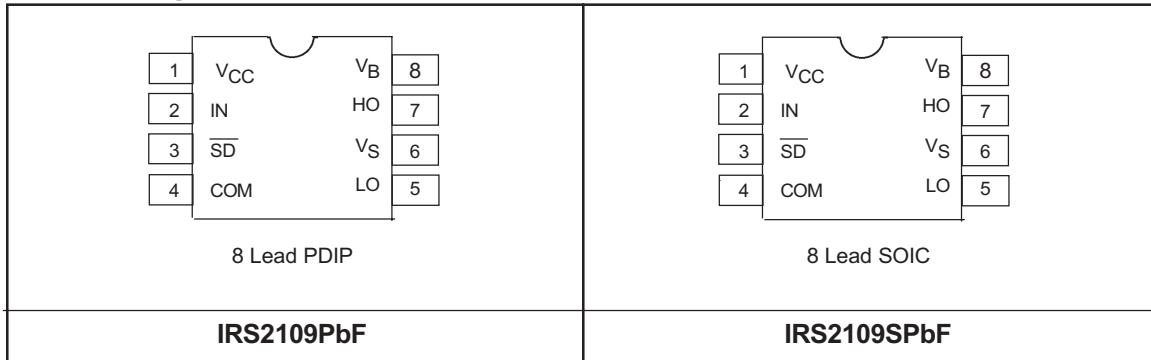
## Functional Block Diagrams



## Lead Definitions

| Symbol          | Description   |
|-----------------|---|
| IN              | Logic input for high-side and low-side gate driver outputs (HO and LO), in phase with HO (referenced to COM for IRS2109 and VSS for IRS21094) |
| $\overline{SD}$ | Logic input for shutdown (referenced to COM for IRS2109 and VSS for IRS21094)   |
| DT              | Programmable deadtime lead, referenced to VSS. (IRS21094 only)  |
| VSS             | Logic ground (IRS21094 only)  |
| $V_B$           | High-side floating supply   |
| HO              | High-side gate drive output   |
| $V_S$           | High-side floating supply return  |
| $V_{CC}$        | Low-side and logic fixed supply   |
| LO              | Low-side gate drive output  |
| COM             | Low-side return   |

## Lead Assignments



# IRS2109/IRS21094(S)PbF

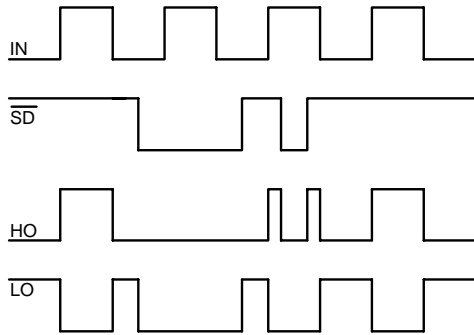


Figure 1. Input/Output Timing Diagram

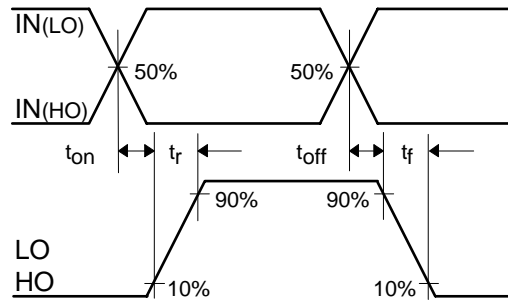


Figure 2. Switching Time Waveform Definitions

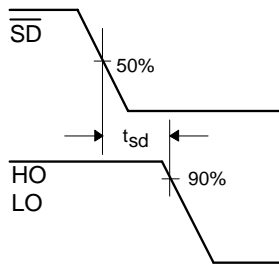


Figure 3. Shutdown Waveform Definitions

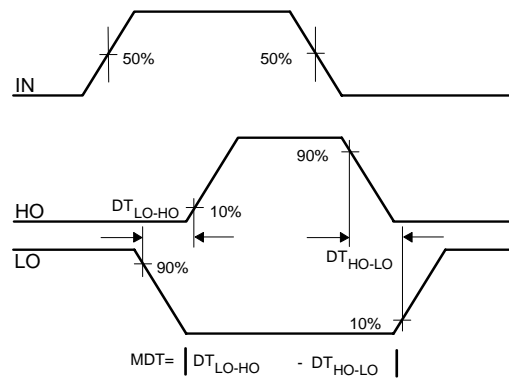


Figure 4. Deadtime Waveform Definitions

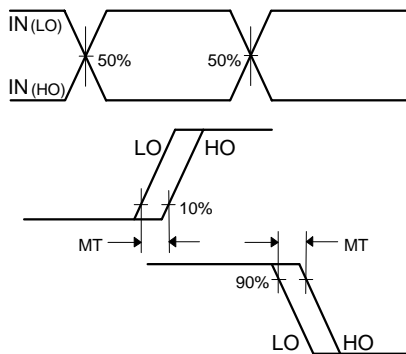
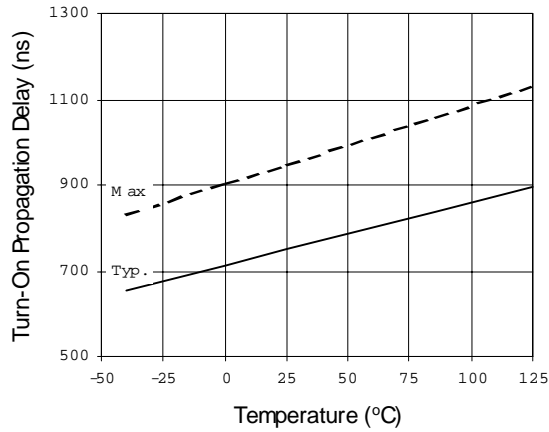
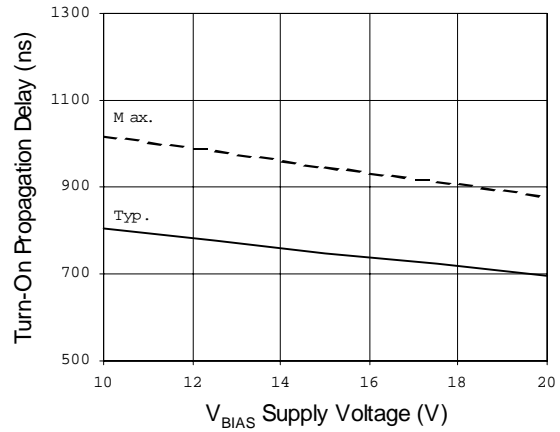


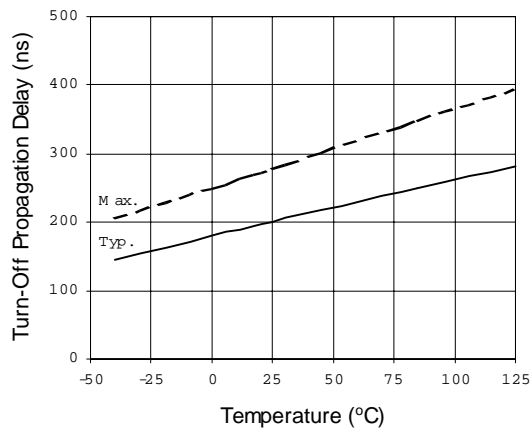
Figure 5. Delay Matching Waveform Definitions



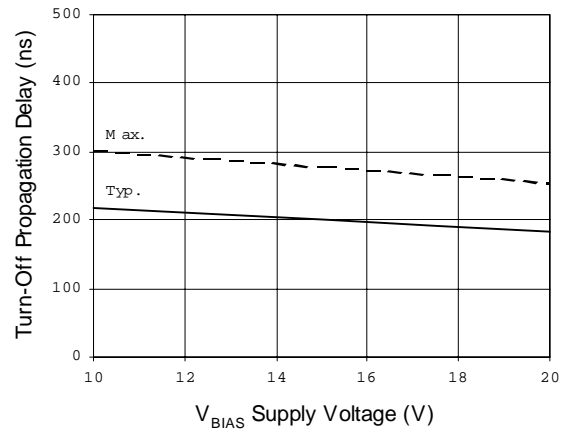
**Figure 6A. Turn-On Propagation Delay vs. Temperature**



**Figure 6B. Turn-On Propagation Delay vs. Supply Voltage**

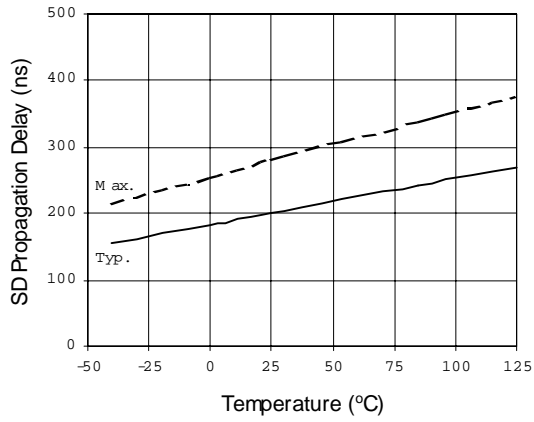


**Figure 7A. Turn-Off Propagation Delay vs. Temperature**

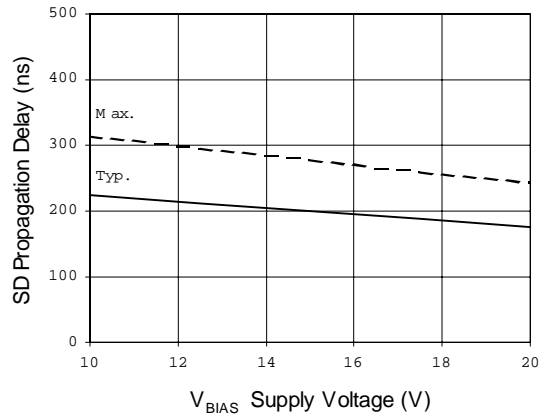


**Figure 7B. Turn-Off Propagation Delay vs. Supply Voltage**

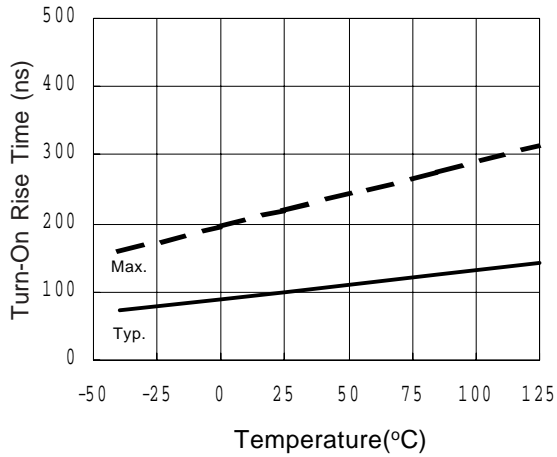




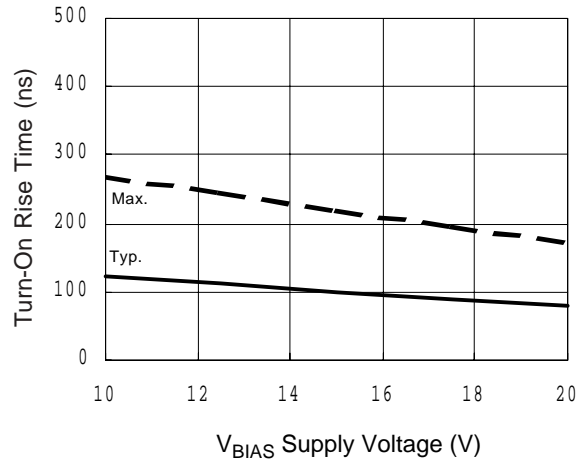
**Figure 8A. SD Propagation Delay vs. Temperature**



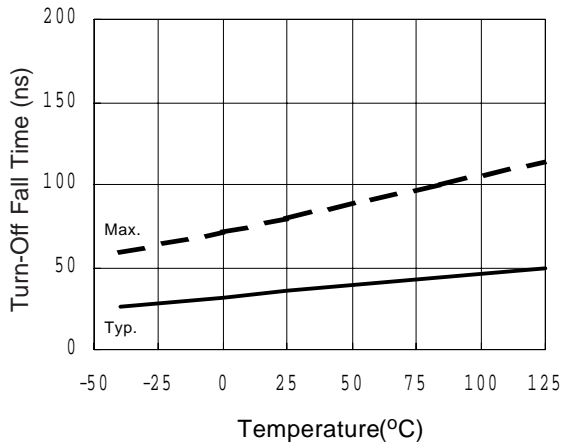
**Figure 8B. SD Propagation Delay vs. Supply Voltage**



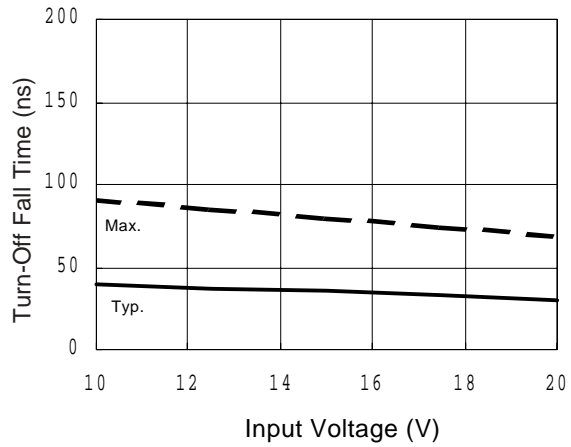
**Figure 9A. Turn-On Rise Time vs. Temperature**



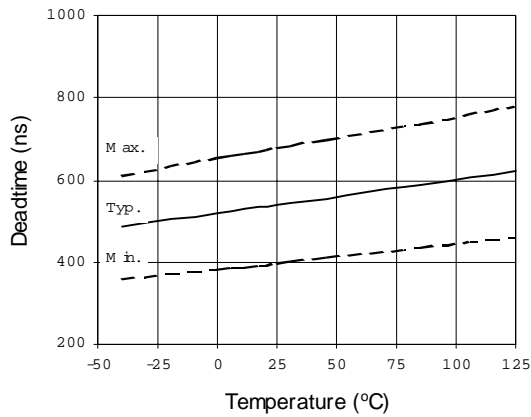
**Figure 9B. Turn-On Rise Time vs. Supply Voltage**



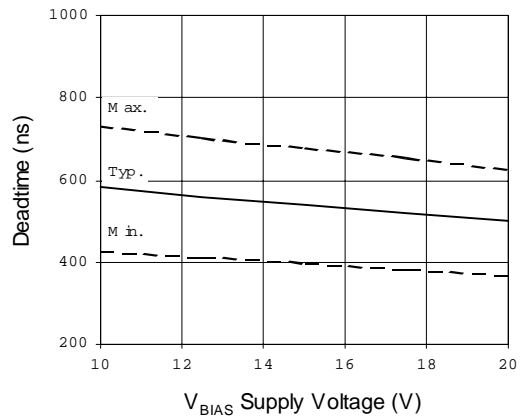
**Figure 10A. Turn-Off Fall Time vs. Temperature**



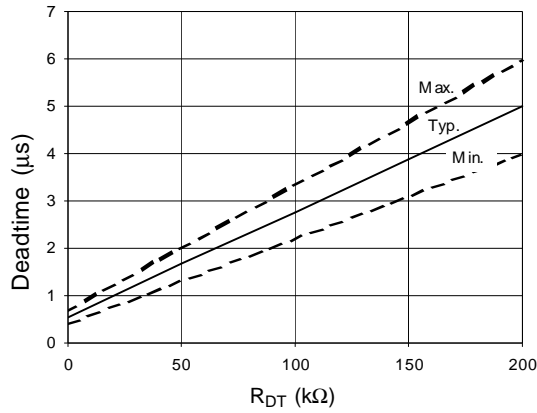
**Figure 10B. Turn-Off Fall Time vs. Supply Voltage**



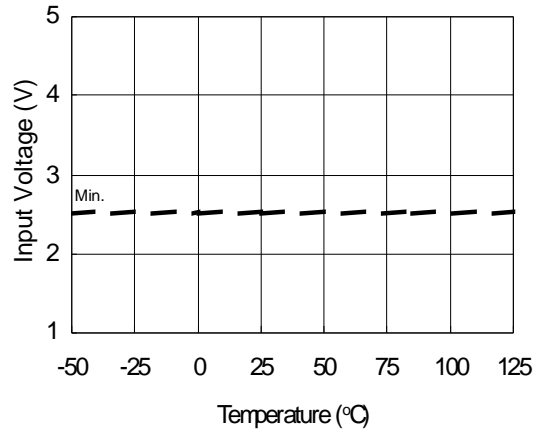
**Figure 11A. Deadtime vs. Temperature**



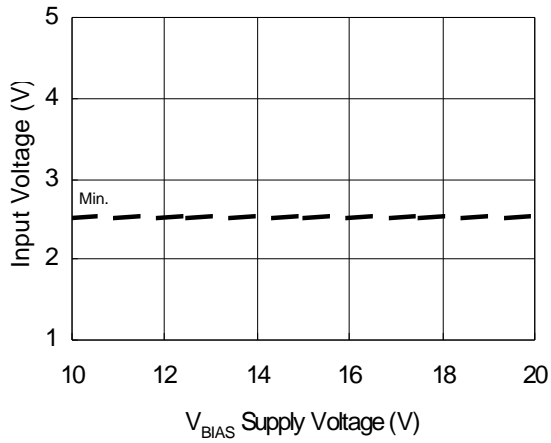
**Figure 11B. Deadtime vs. Supply Voltage**



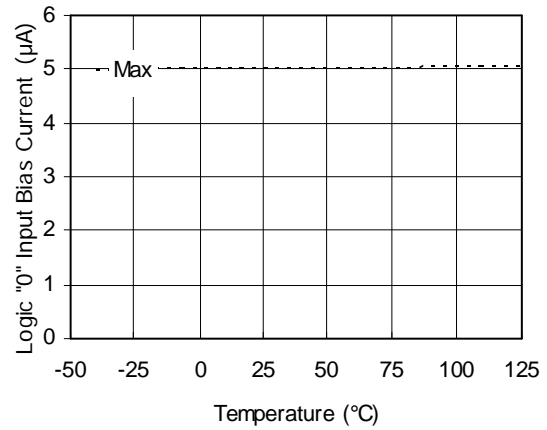
**Figure 11C. Deadtime vs. RDT  
 (IR21094 only)**



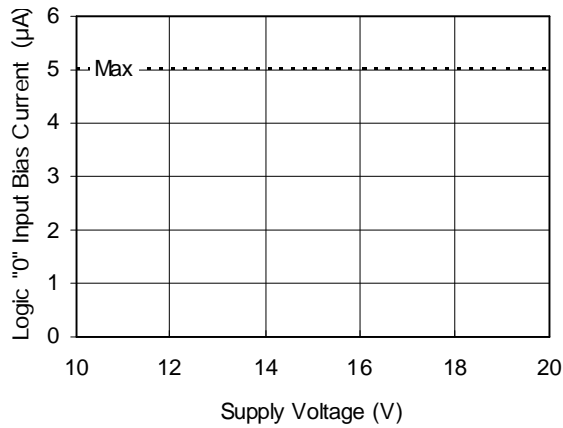
**Figure 12A. Logic "1" Input Voltage  
 vs. Temperature**



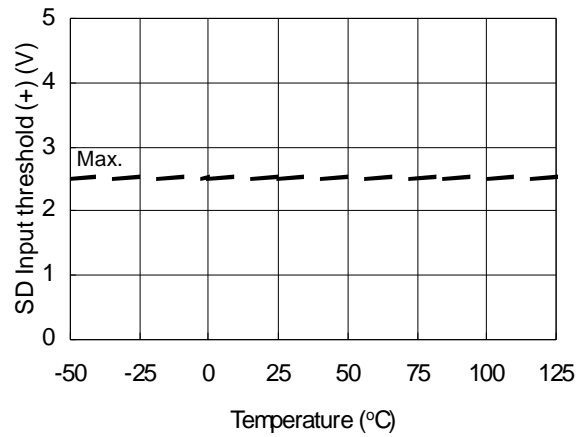
**Figure 12B. Logic "1" Input Voltage  
 vs. Supply Voltage**



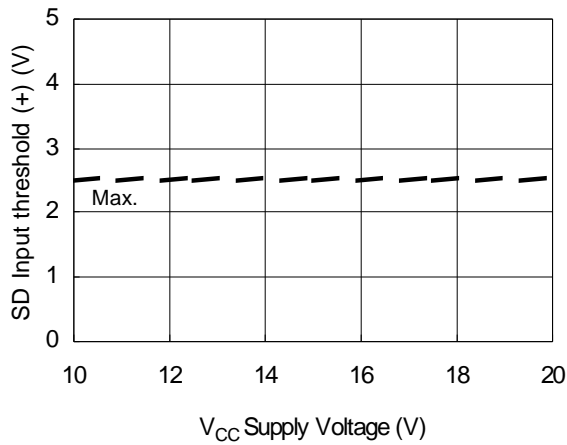
**Figure 13A. Logic "0" Input Bias Current  
 vs. Temperature**



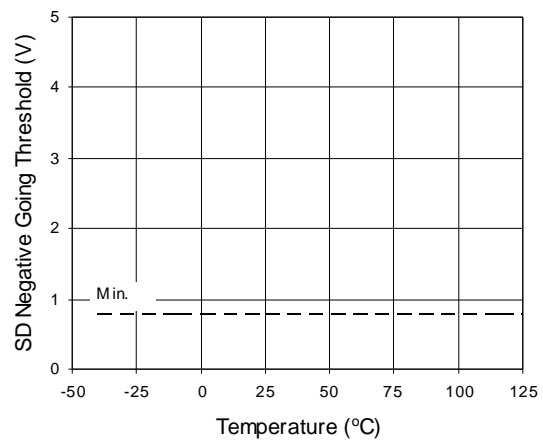
**Figure 13B. Logic "0" Input Bias Current vs. Voltage**



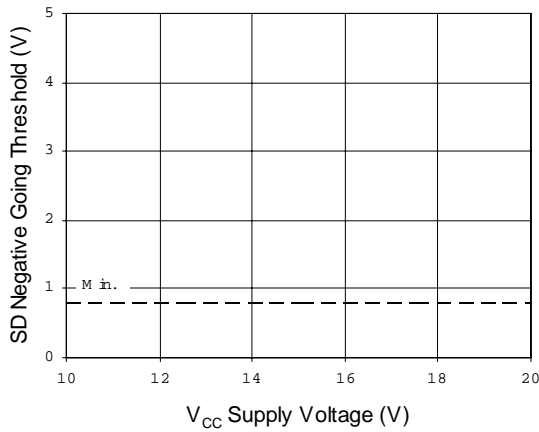
**Figure 14A. SD Input Positive Going Threshold (+) vs. Temperature**



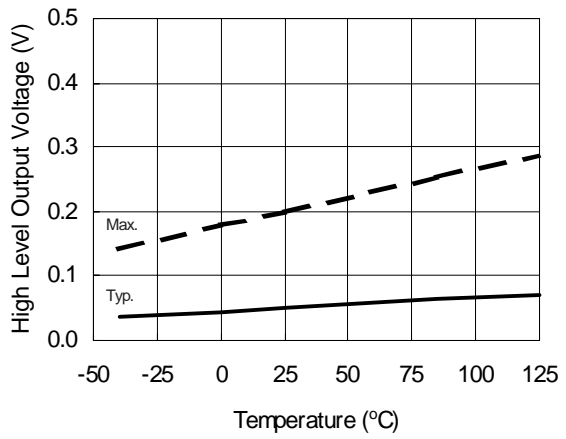
**Figure 14B. SD Input Positive Going Threshold (+) vs. Supply Voltage**



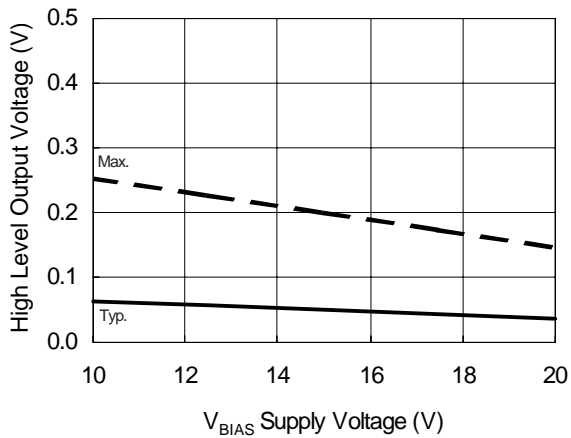
**Figure 15A. SD Negative Going Threshold vs. Temperature**



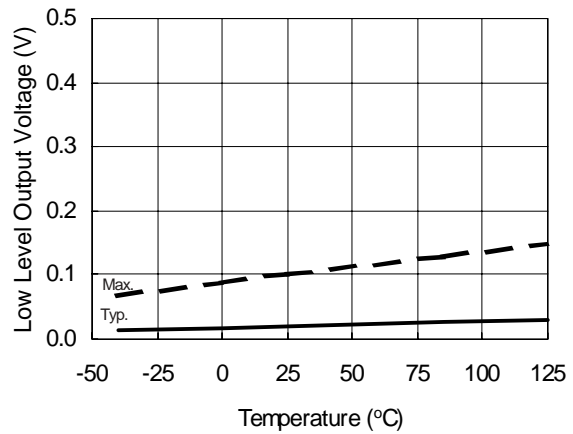
**Figure 15B. SD Negative Going Threshold vs. Supply Voltage**



**Figure 16A. High Level Output Voltage vs. Temperature**



**Figure 16B. High Level Output Voltage vs. Supply Voltage**



**Figure 17A. Low Level Output Voltage vs. Temperature**

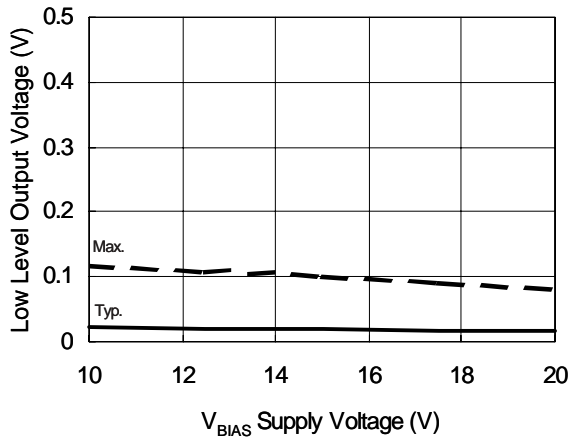


Figure 17B. Low Level Output Voltage vs. Supply Voltage

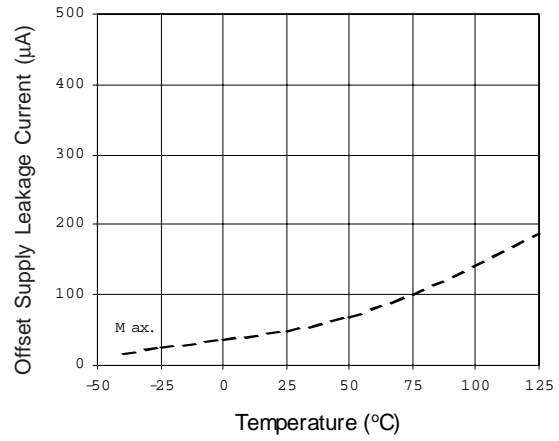


Figure 18A. Offset Supply Leakage Current vs. Temperature

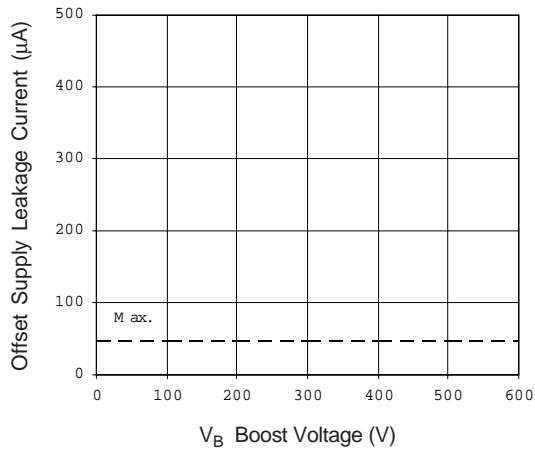


Figure 18B. Offset Supply Leakage Current vs. Boost Voltage

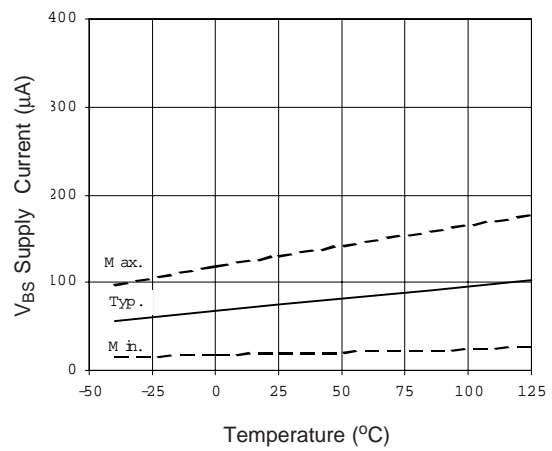


Figure 19A. V<sub>BS</sub> Supply Current vs. Temperature

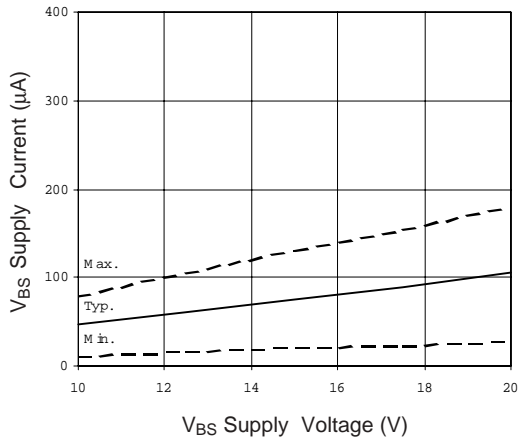


Figure 19B. VBS Supply Current vs. Supply Voltage

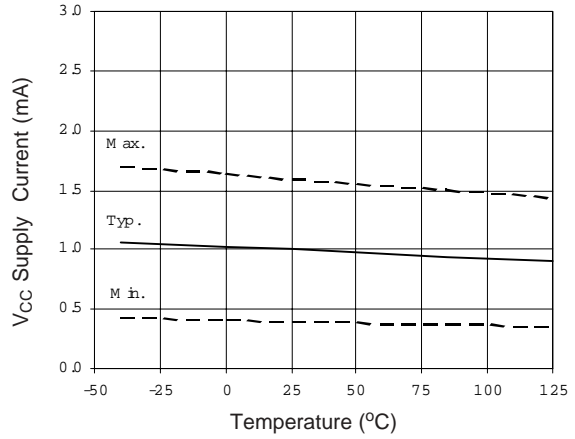


Figure 20A. VCC Supply Current vs. Temperature

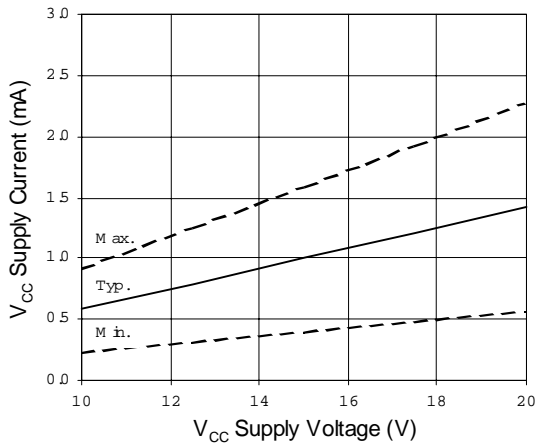


Figure 20B. VCC Supply Current vs. VCC Supply Voltage

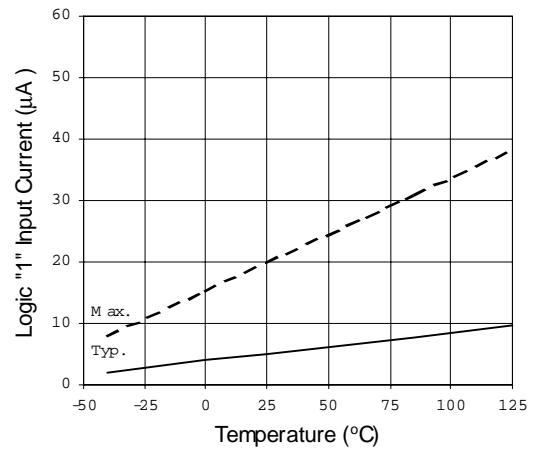
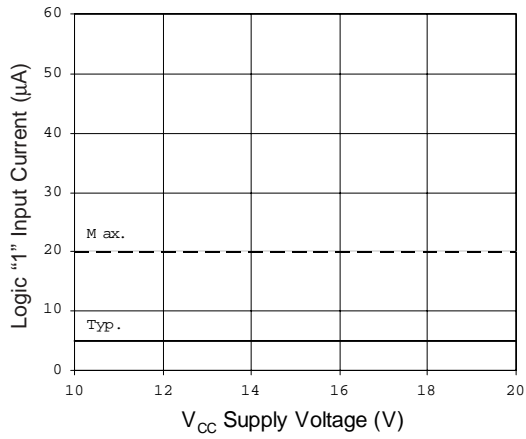
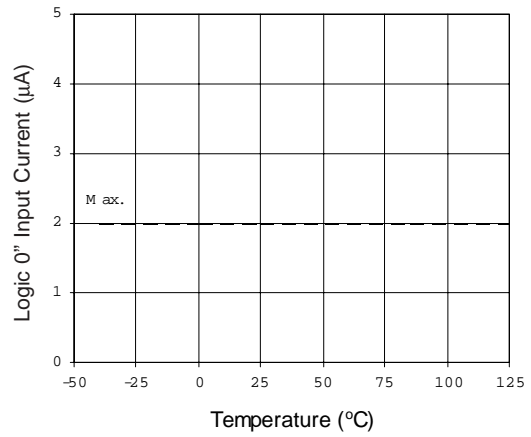


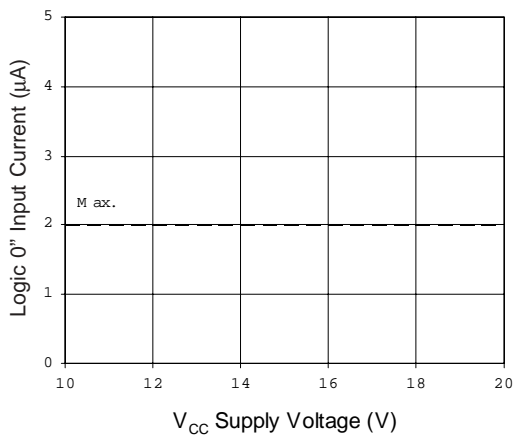
Figure 21A. Logic "1" Input Current vs. Temperature



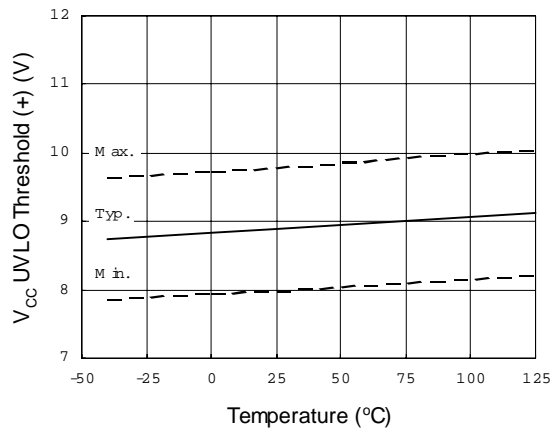
**Figure 21B. Logic "1" Input Current vs. Supply Voltage**



**Figure 22A. Logic "0" Input Current vs. Temperature**



**Figure 22B. Logic "0" Input Current vs. Supply Voltage**



**Figure 23. V<sub>CC</sub> Undervoltage Threshold (+) vs. Temperature**



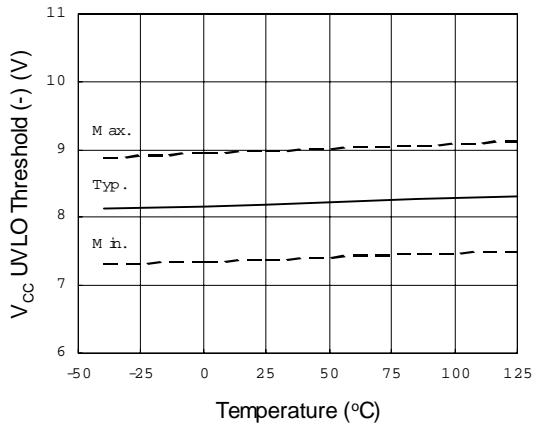


Figure 24. VCC Undervoltage Threshold (-) vs. Temperature

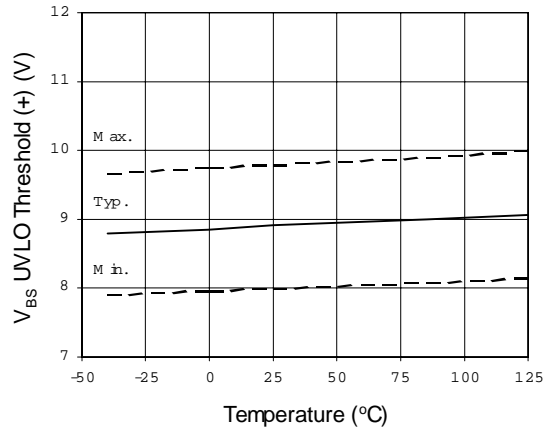


Figure 25. VBS Undervoltage Threshold (+) vs. Temperature

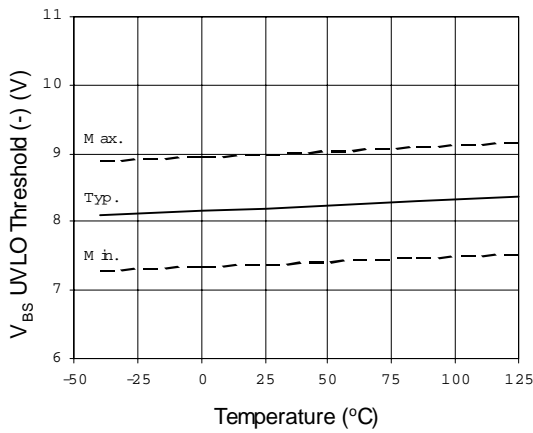


Figure 26. VBS Undervoltage Threshold (-) vs. Temperature

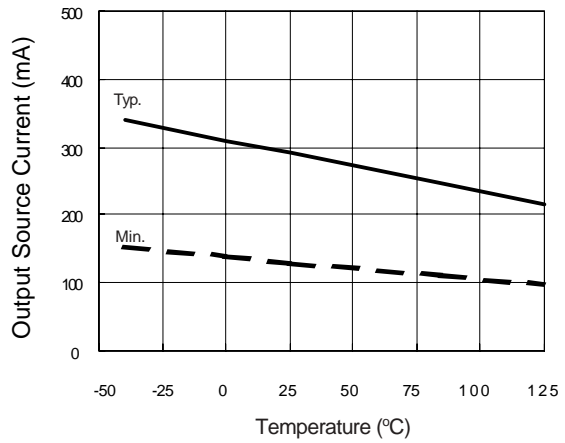
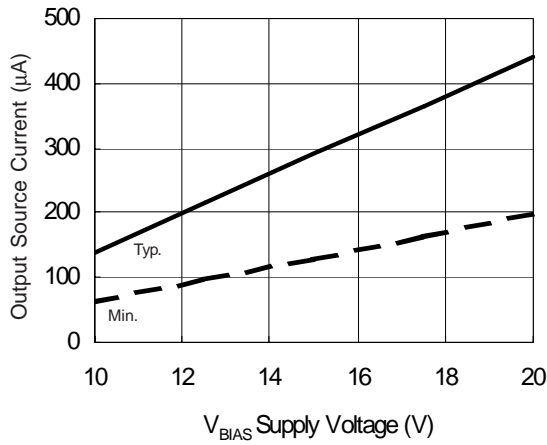
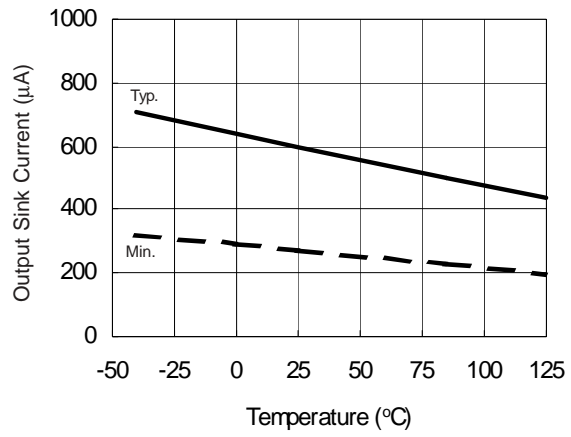


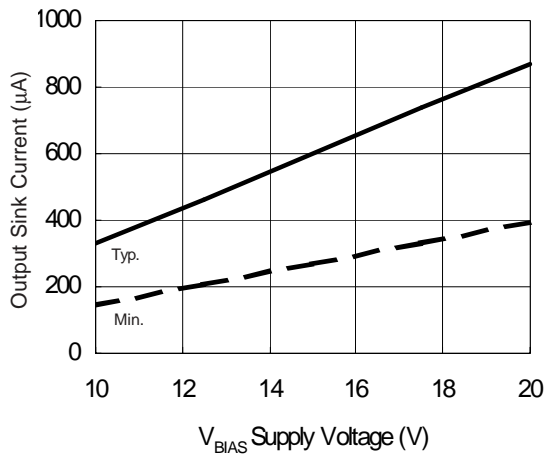
Figure 27A. Output Source Current vs. Temperature



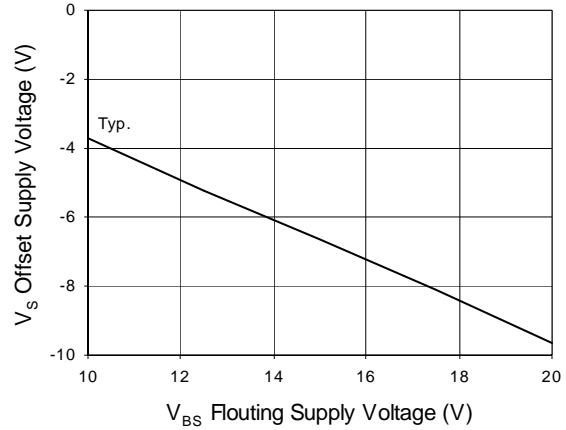
**Figure 27B. Output Source Current vs. Supply Voltage**



**Figure 28A. Output Sink Current vs. Temperature**



**Figure 28B. Output Sink Current vs. Supply Voltage**



**Figure 29. Maximum V<sub>S</sub> Negative Offset vs. Supply Voltage**

# IRS2109/IRS21094(S)PbF

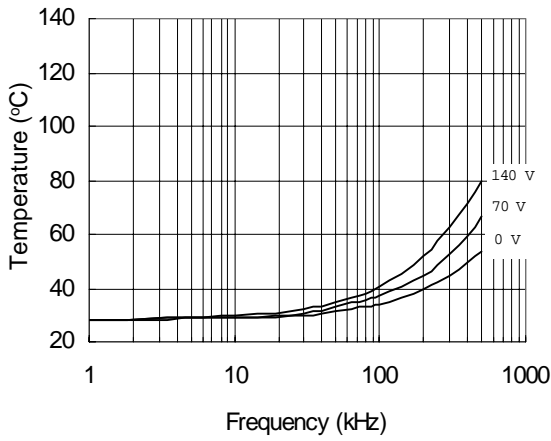


Figure 30. IRS2109 vs Frequency (IRFBC20)  
 $R_{gate} = 33 \Omega$ ,  $V_{CC} = 15 V$

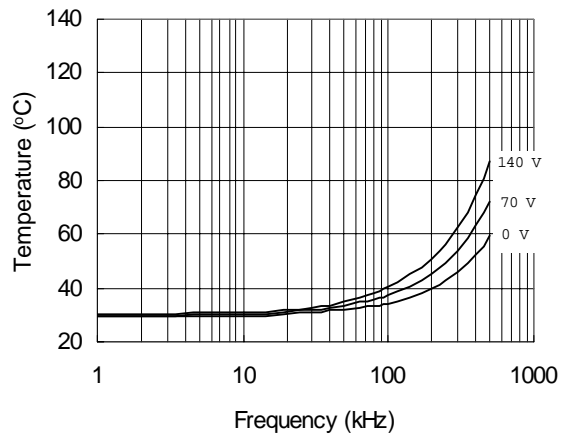


Figure 31. IRS2109 vs Frequency (IRFBC30)  
 $R_{gate} = 22 \Omega$ ,  $V_{CC} = 15 V$

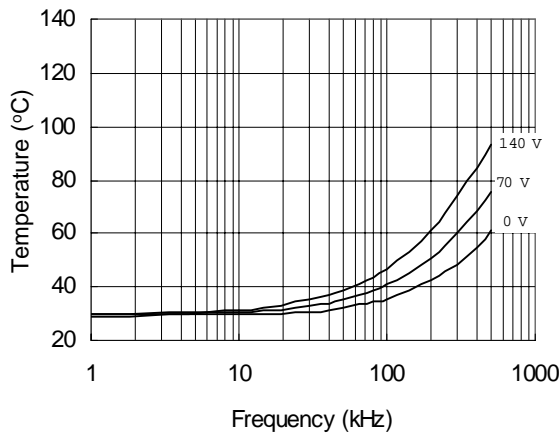


Figure 32. IRS2109 vs Frequency (IRFBC40)  
 $R_{gate} = 15 \Omega$ ,  $V_{CC} = 15 V$

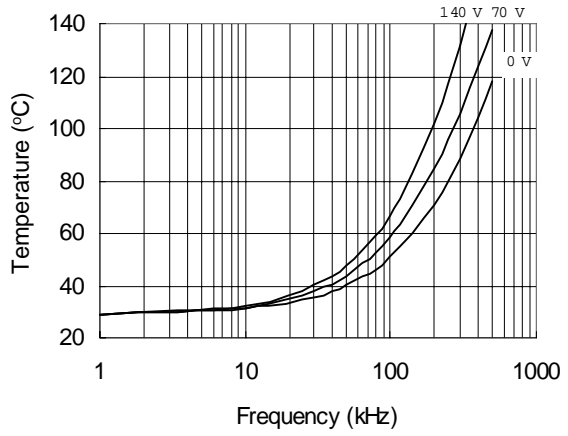
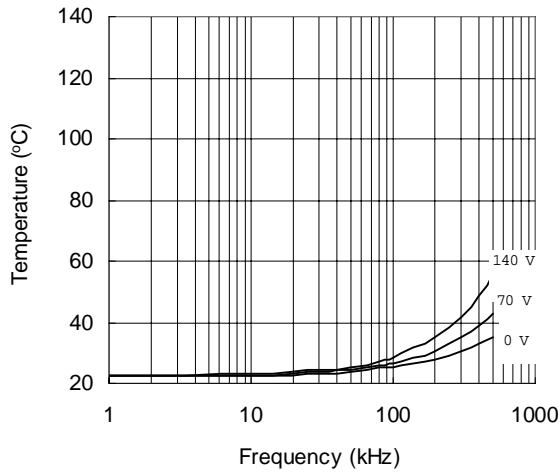
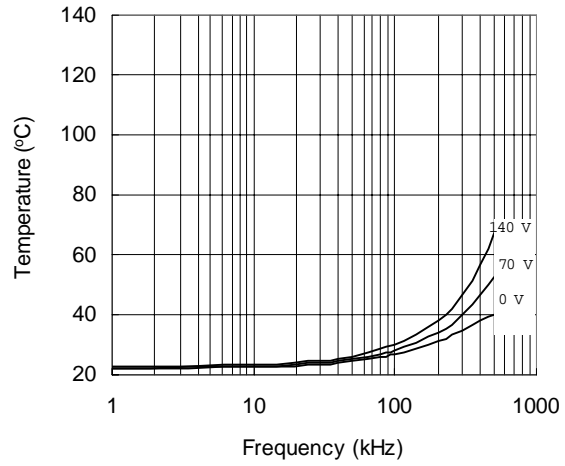


Figure 33. IRS2109 vs Frequency (IRFPE50)  
 $R_{gate} = 10 \Omega$ ,  $V_{CC} = 15 V$

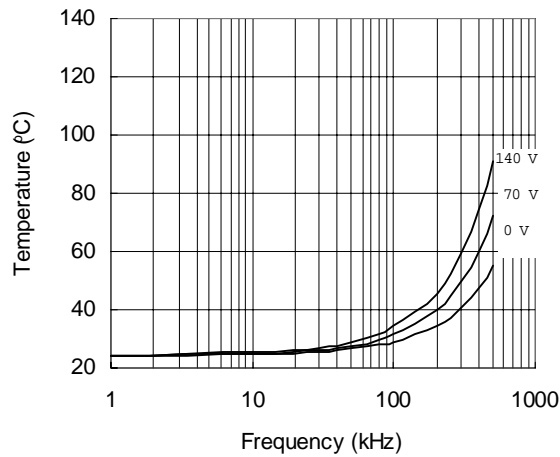
# IRS2109/IRS21094(S)PbF



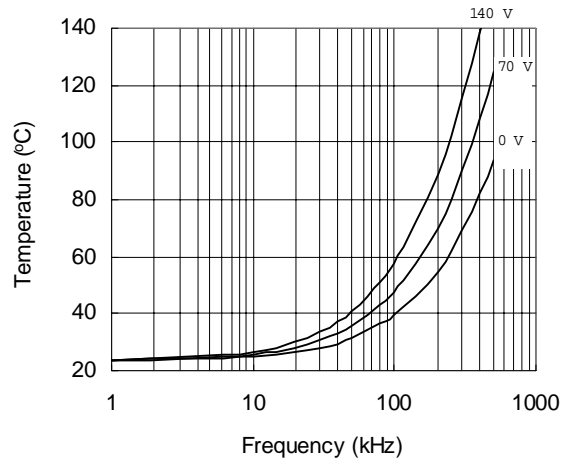
**Figure 34. IRS21094 vs. Frequency (IRFBC20),  
 $R_{gate}=33 \Omega$ ,  $V_{CC}=15 V$**



**Figure 35. IRS21094 vs. Frequency (IRFBC30),  
 $R_{gate}=22 \Omega$ ,  $V_{CC}=15 V$**

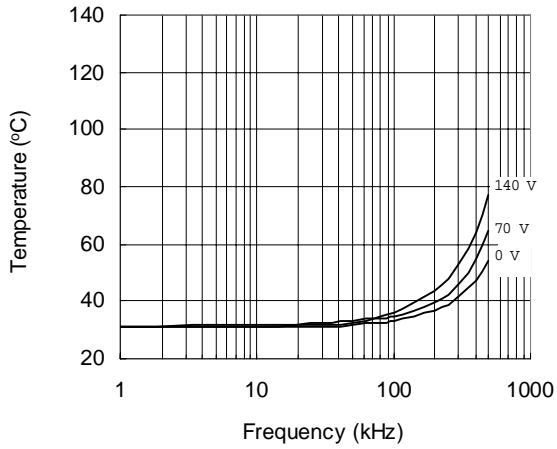


**Figure 36. IRS21094 vs. Frequency (IRFBC40),  
 $R_{gate}=15 \Omega$ ,  $V_{CC}=15 V$**

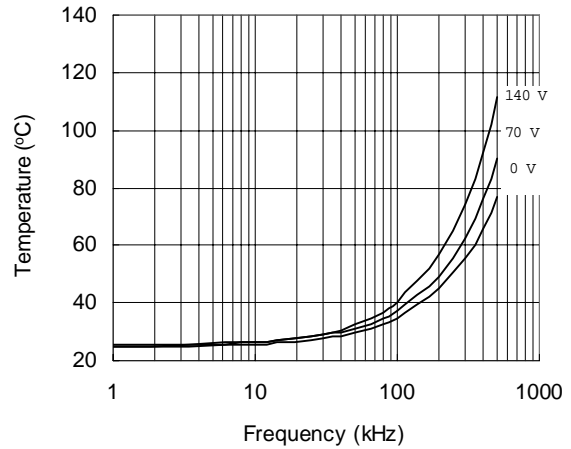


**Figure 37. IRS21094 vs. Frequency (IRFPE50),  
 $R_{gate}=10 \Omega$ ,  $V_{CC}=15 V$**

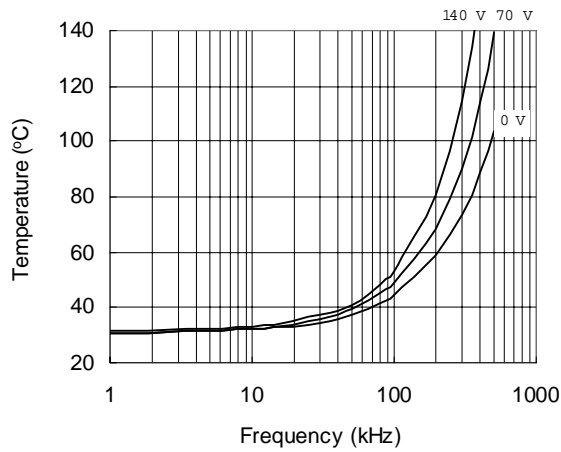
# IRS2109/IRS21094(S)PbF



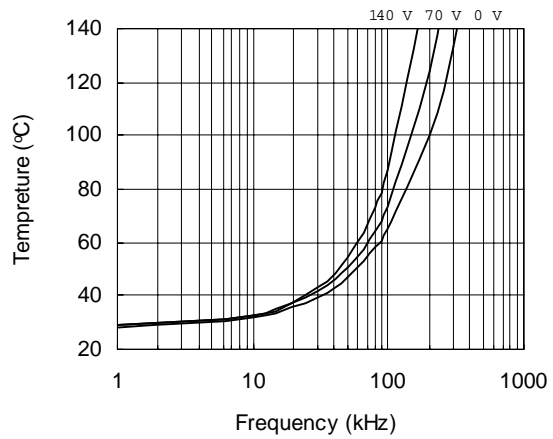
**Figure 38. IRS2109S vs. Frequency (IRFBC20),  
 $R_{gate}=33 \Omega$ ,  $V_{CC}=15 V$**



**Figure 39. IRS2109S vs. Frequency (IRFBC30),  
 $R_{gate}=22 \Omega$ ,  $V_{CC}=15 V$**



**Figure 40. IRS2109S vs. Frequency (IRFBC40),  
 $R_{gate}=15 \Omega$ ,  $V_{CC}=15 V$**



**Figure 41. IRS2109S vs. Frequency (IRFPE50),  
 $R_{gate}=10 \Omega$ ,  $V_{CC}=15 V$**

# IRS2109/IRS21094(S)PbF

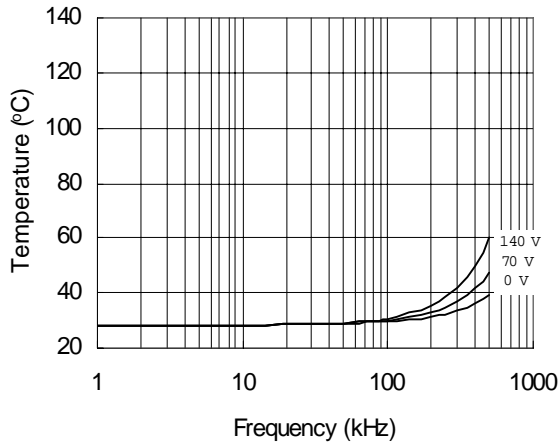


Figure 42. IRS21094S vs. Frequency (IRFBC20),  
 $R_{gate}=33 \Omega$ ,  $V_{cc}=15 \text{ V}$

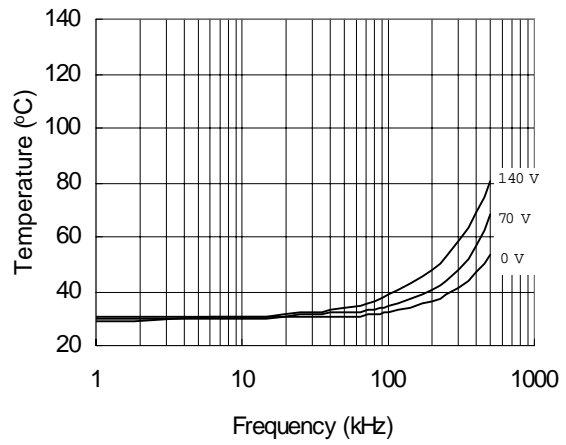


Figure 43. IRS21094S vs. Frequency (IRFBC30),  
 $R_{gate}=22 \Omega$ ,  $V_{cc}=15 \text{ V}$

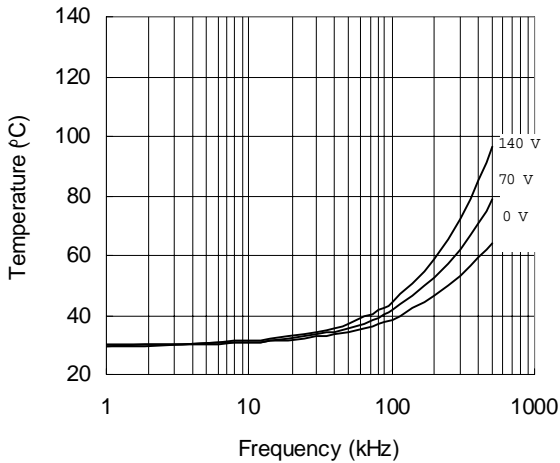


Figure 44. IRS21094S vs. Frequency (IRFBC40),  
 $R_{gate}=15 \Omega$ ,  $V_{cc}=15 \text{ V}$

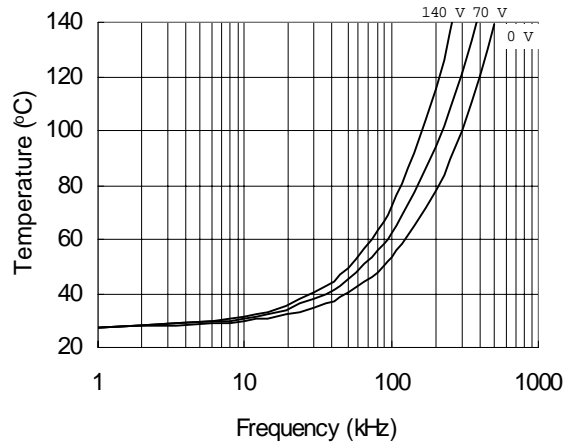
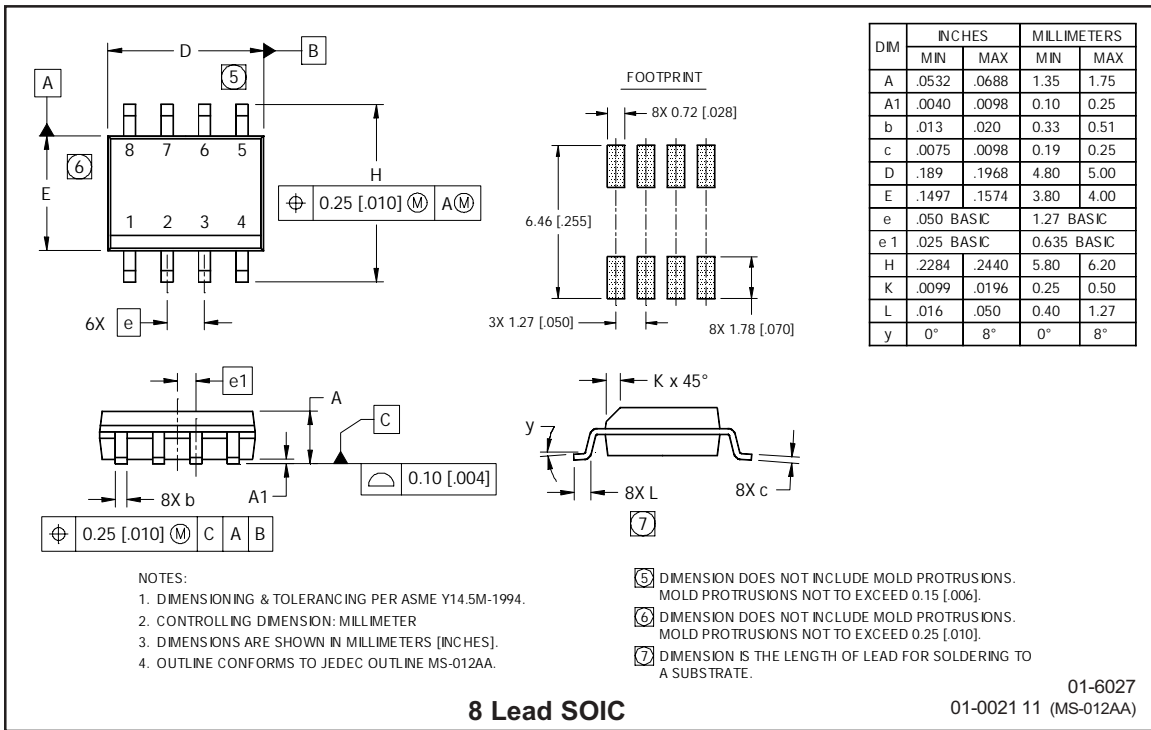
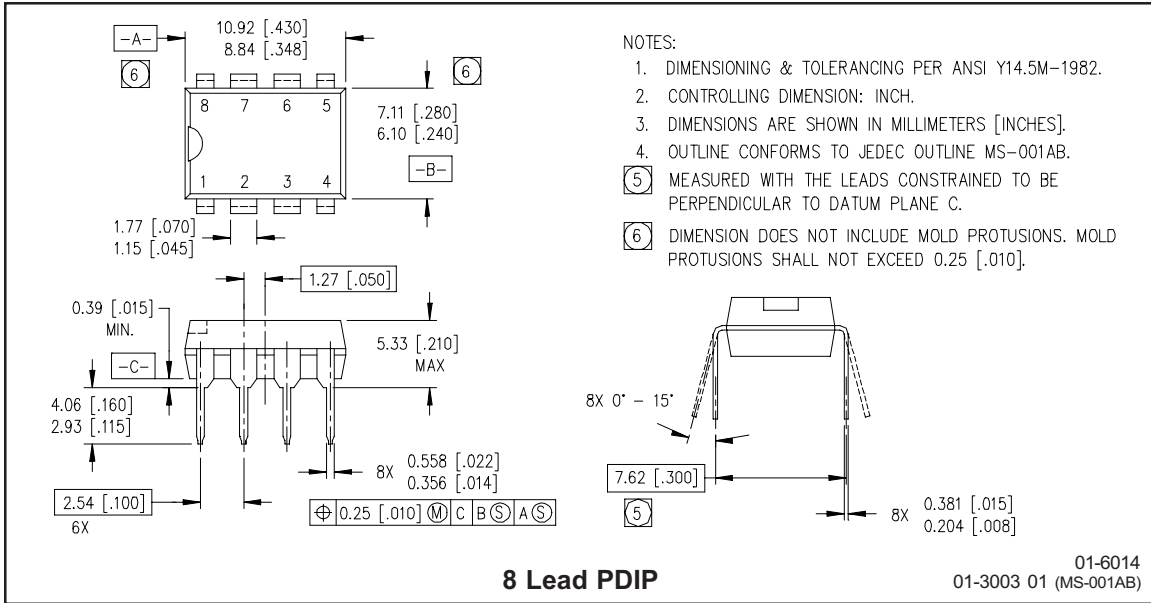
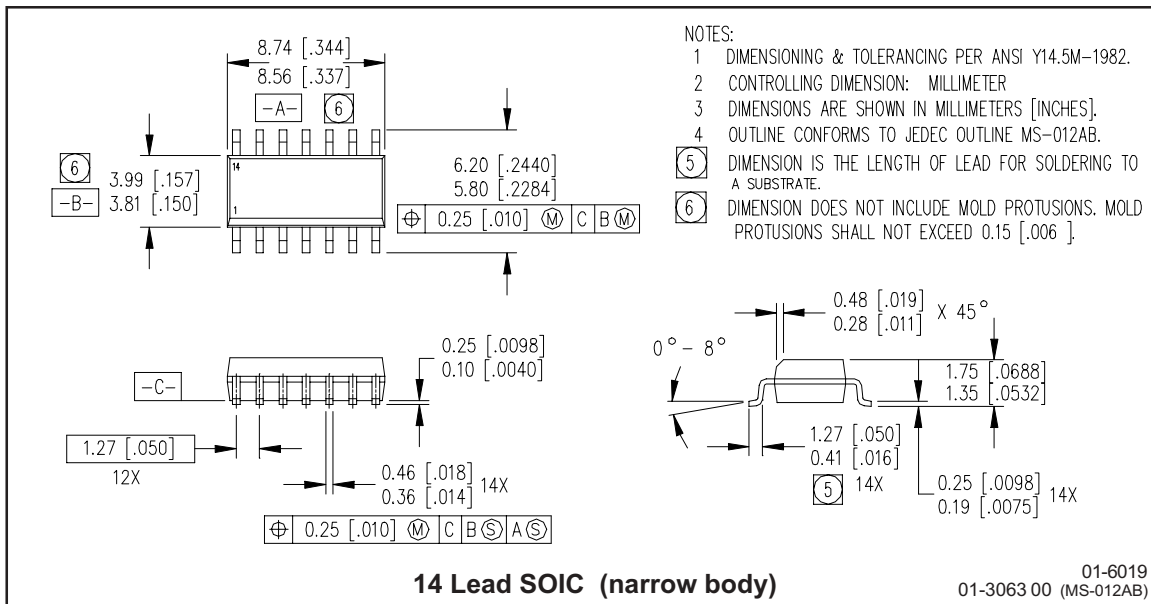
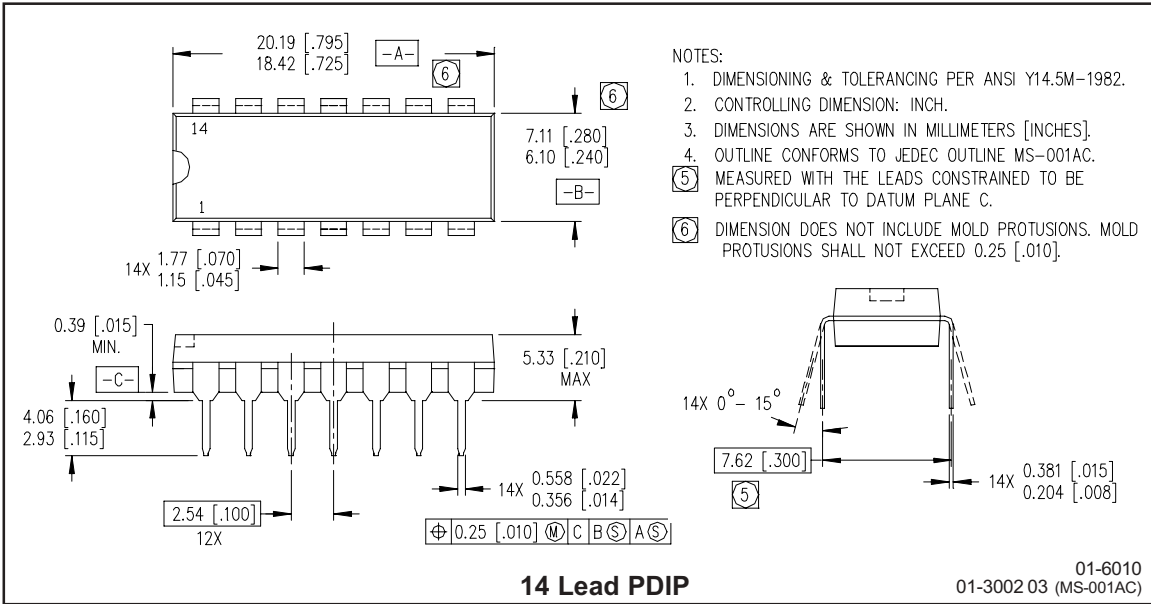


Figure 45. IRS21094S vs. Frequency (IRFPE50),  
 $R_{gate}=10 \Omega$ ,  $V_{cc}=15 \text{ V}$

## Case Outlines

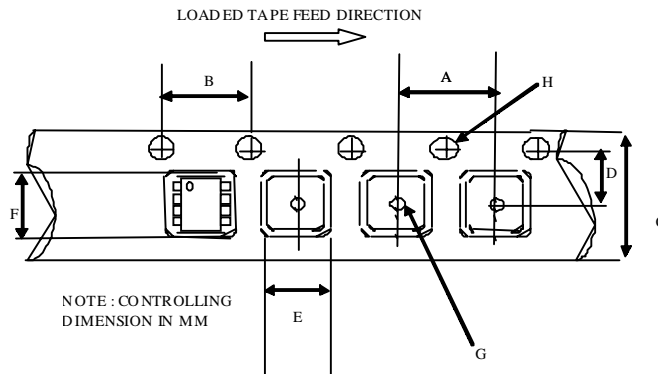


# IRS2109/IRS21094(S)PbF



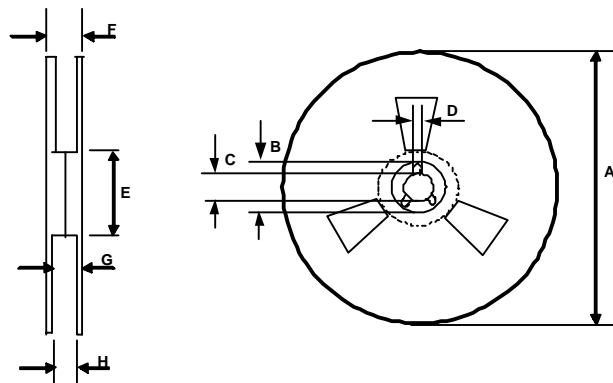


## Tape & Reel 8-lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

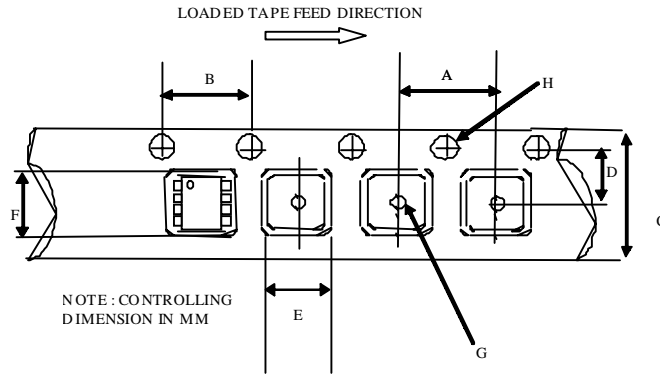
| Code | Metric |       | Imperial |       |
|------|--------|-------|----------|-------|
|      | Min    | Max   | Min      | Max   |
| A    | 7.90   | 8.10  | 0.311    | 0.318 |
| B    | 3.90   | 4.10  | 0.153    | 0.161 |
| C    | 11.70  | 12.30 | 0.46     | 0.484 |
| D    | 5.45   | 5.55  | 0.214    | 0.218 |
| E    | 6.30   | 6.50  | 0.248    | 0.255 |
| F    | 5.10   | 5.30  | 0.200    | 0.208 |
| G    | 1.50   | n/a   | 0.059    | n/a   |
| H    | 1.50   | 1.60  | 0.059    | 0.062 |



REEL DIMENSIONS FOR 8SOICN

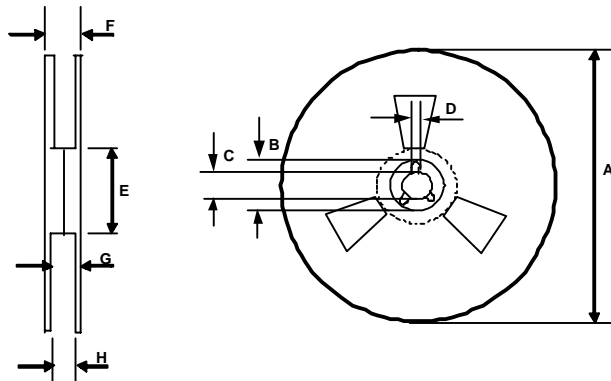
| Code | Metric |        | Imperial |        |
|------|--------|--------|----------|--------|
|      | Min    | Max    | Min      | Max    |
| A    | 329.60 | 330.25 | 12.976   | 13.001 |
| B    | 20.95  | 21.45  | 0.824    | 0.844  |
| C    | 12.80  | 13.20  | 0.503    | 0.519  |
| D    | 1.95   | 2.45   | 0.767    | 0.096  |
| E    | 98.00  | 102.00 | 3.858    | 4.015  |
| F    | n/a    | 18.40  | n/a      | 0.724  |
| G    | 14.50  | 17.10  | 0.570    | 0.673  |
| H    | 12.40  | 14.40  | 0.488    | 0.566  |

## Tape & Reel 14-lead SOIC



CARRIER TAPE DIMENSION FOR 14SOICN

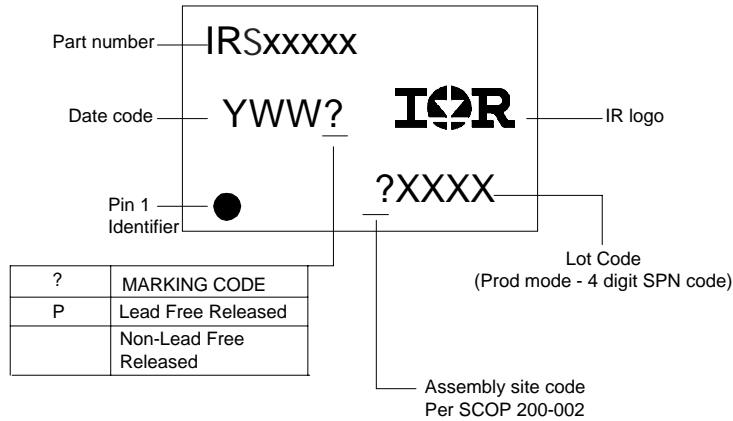
| Code | Metric |       | Imperial |       |
|------|--------|-------|----------|-------|
|      | Min    | Max   | Min      | Max   |
| A    | 7.90   | 8.10  | 0.311    | 0.318 |
| B    | 3.90   | 4.10  | 0.153    | 0.161 |
| C    | 15.70  | 16.30 | 0.618    | 0.641 |
| D    | 7.40   | 7.60  | 0.291    | 0.299 |
| E    | 6.40   | 6.60  | 0.252    | 0.260 |
| F    | 9.40   | 9.60  | 0.370    | 0.378 |
| G    | 1.50   | n/a   | 0.059    | n/a   |
| H    | 1.50   | 1.60  | 0.059    | 0.062 |



REEL DIMENSIONS FOR 14SOICN

| Code | Metric |        | Imperial |        |
|------|--------|--------|----------|--------|
|      | Min    | Max    | Min      | Max    |
| A    | 329.60 | 330.25 | 12.976   | 13.001 |
| B    | 20.95  | 21.45  | 0.824    | 0.844  |
| C    | 12.80  | 13.20  | 0.503    | 0.519  |
| D    | 1.95   | 2.45   | 0.767    | 0.096  |
| E    | 98.00  | 102.00 | 3.858    | 4.015  |
| F    | n/a    | 22.40  | n/a      | 0.881  |
| G    | 18.50  | 21.10  | 0.728    | 0.830  |
| H    | 16.40  | 18.40  | 0.645    | 0.724  |

## LEADFREE PART MARKING INFORMATION



## ORDER INFORMATION

- 8-Lead PDIP IRS2109PbF
- 8-Lead SOIC IRS2109SPbF
- 8-Lead SOIC Tape & Reel IRS2109STRPbF
  
- 14-Lead PDIP IRS21094PbF
- 14-Lead SOIC IRS21094SPbF
- 14-Lead SOIC Tape & Reel IRS21094STRPbF

SOIC8 &14 are MSL2 qualified.  
 This product has been designed and qualified for the industrial level.  
 Qualification standards can be found at [www.irf.com](http://www.irf.com)

**IR WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105  
 Data and specifications subject to change without notice. 12/4/2006

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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